BYV29G-600

Ultrafast power diode

29 September 2018 Product data sheet

1. General description

Ultrafast power diode in a SOT226A (I2PAK) plastic package

2. Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward voltage drop
- Low on-state losses
- Low profile package facilitating compact designs
- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- Output rectifiers in high-frequency switched-mode power supplies

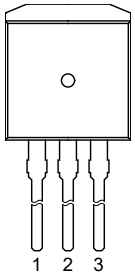
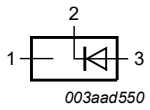
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_R	reverse voltage	DC		-	-	600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_{mb} \leq$ 123 °C; SQW; Fig. 1; Fig. 2		-	-	9	A
I_{FSM}	non-repetitive peak forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; SIN		-	-	77	A
		t_p = 10 ms; $T_{j(init)}$ = 25 °C; SIN		-	-	70	A
Static characteristics							
V_F	forward voltage	I_F = 8 A; T_j = 25 °C; Fig. 4		-	1.12	1.25	V
		I_F = 20 A; T_j = 25 °C; Fig. 4		-	1.31	1.45	V
		I_F = 8 A; T_j = 150 °C		-	0.97	1.11	V
Dynamic characteristics							
t_{rr}	reverse recovery time	I_F = 1 A; V_R = 30 V; dI_F/dt = 100 A/µs; T_j = 25 °C; Fig. 4		-	50	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	no connection	 I2PAK (SOT226A)	
2	K	cathode		
3	A	anode		
mb	K	mounting base; cathode		

6. Ordering information

Table 3. Ordering information

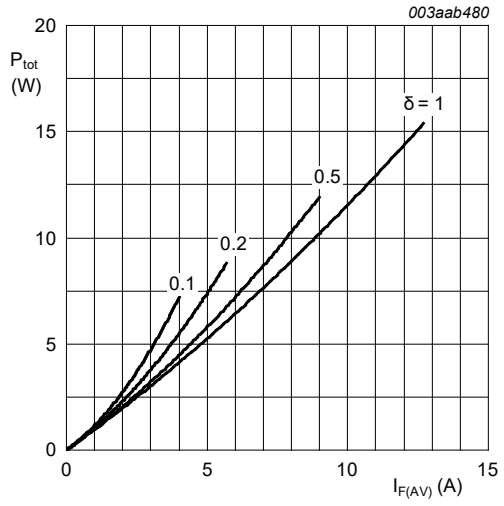
Type number	Package		
	Name	Description	Version
BYV29G-600	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A

7. Limiting values

Table 4. Limiting values

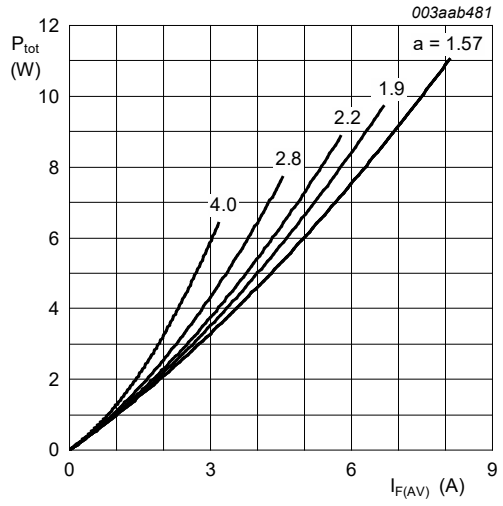
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage			-	600	V
V_{RWM}	crest working reverse voltage			-	600	V
V_R	reverse voltage	DC		-	600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_{mb} \leq 123$ °C; SQW; Fig. 1; Fig. 2		-	9	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ µs		-	18	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; SIN		-	77	A
		$t_p = 10$ ms; $T_{j(init)} = 25$ °C; SIN		-	70	A
T_{stg}	storage temperature			-40	150	°C
T_j	junction temperature			-	150	°C



$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)} / I_{F(AV)}$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j\text{-}mb)}$	thermal resistance from junction to mounting base	with heatsink compound; Fig. 3		-	-	2.5	K/W
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient free air			-	60	-	K/W

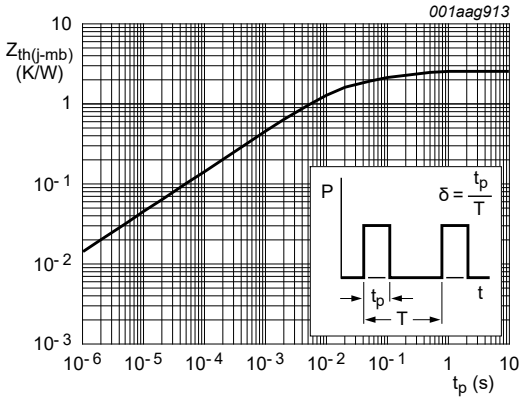
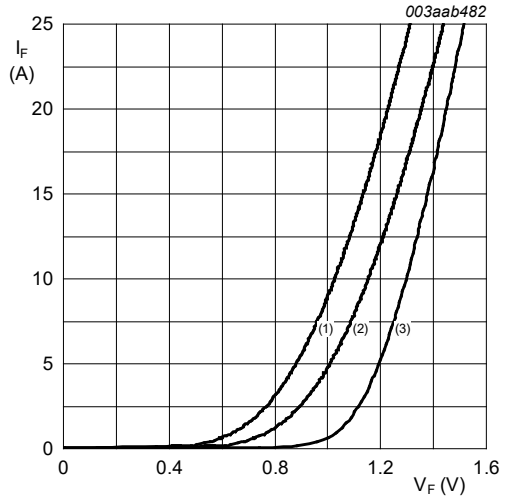


Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	I_F = 8 A; T_j = 25 °C; Fig. 4		-	1.12	1.25	V
		I_F = 20 A; T_j = 25 °C; Fig. 4		-	1.31	1.45	V
		I_F = 8 A; T_j = 150 °C; Fig. 4		-	0.97	1.11	V
I_R	reverse current	V_R = 600 V		-	2	50	µA
		V_R = 600 V; T_j = 100 °C		-	0.1	0.35	mA
Dynamic characteristics							
t_{rr}	reverse recovery time	I_F = 1 A; V_R = 30 V; dI_F/dt = 100 A/µs; T_j = 25 °C; Fig. 5		-	50	60	ns
I_{RM}	peak reverse recovery current	I_F = 10 A; V_R = 30 V; dI_F/dt = 50 A/µs; Fig. 5		-	3	5.5	A
Q_r	recovered charge	I_F = 2 A; V_R = 30 V; dI_F/dt = 20 A/µs; Fig. 5		-	40	70	nC
V_{FR}	forward recovery voltage	I_F = 10 A; dI_F/dt = 10 A/µs; Fig. 6		-	3.2	-	V



(1) T_j = 150 °C; typical values
(2) T_j = 150 °C; maximum values
(3) T_j = 25 °C; maximum values

Fig. 4. Forward current as a function of forward voltage

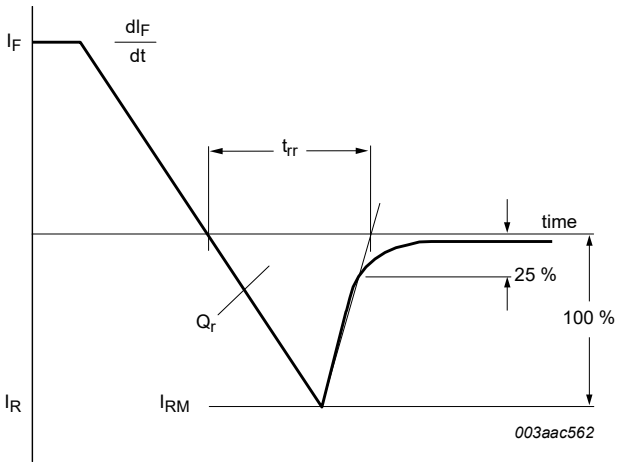


Fig. 5. Reverse recovery definitions; ramp recovery

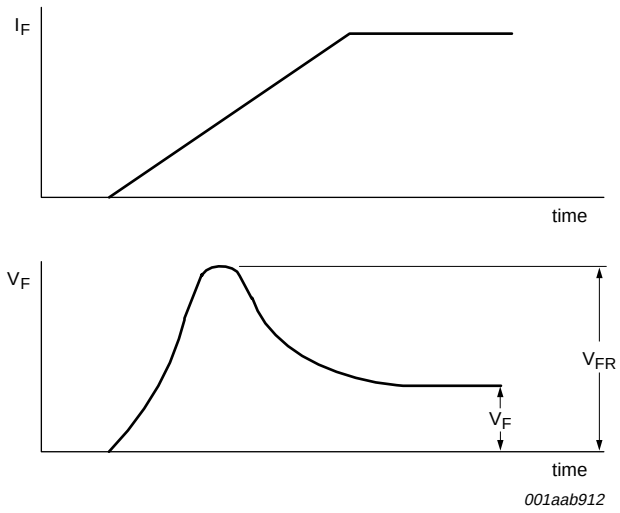
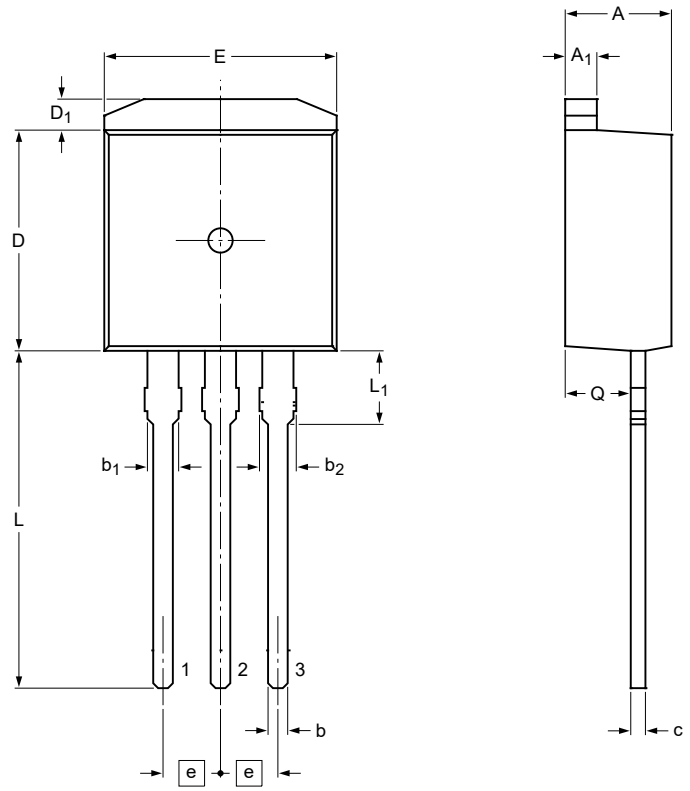


Fig. 6. Forward recovery definitions

10. Package outline

Plastic single-ended package (I2PAK); low-profile 3-lead TO-262 **SOT226A**



Dimensions

Unit		A	A_1	b	b_1	b_2	c	D	D_1	E	e	L	L_1	Q
mm	max	4.7	1.40	0.95	1.40	1.7	0.65	9.4	1.32	10.30	2.54 (REF)	15.0	3.0 (REF)	2.6
	nom													
	min	4.3	1.15	0.70	1.14	1.3	0.45	8.6	1.02	9.65		12.5		2.2

sot226a_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT226A		TO-262				~~09-08-17~~ 09-08-25

Fig. 7. Package outline I2PAK (SOT226A)

11. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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12. Contents

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